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(An Autonomous Institution)

Regulations: A18

CO4

CO<sub>5</sub>

CO6

[2M]

[2M]

[2M]

L1

L4

L2

Code No: 7CC55

Date: 20-August <del>Loza (FN)</del>

B.Tech II-Year II- Semester External Examination, August - 2024 (Supplementary)

DIGITAL ELECTRONICS (CSE and IT)

Time: 3 Hours Max.Marks:70

Note: a) No additional answer sheets will be provided.

- b) All sub-parts of a question must be answered at one place only, otherwise it will not be valued.
- c) Missing data can be assumed suitably.

What are the differences between flip flop and latch

Write the characteristics of PAL and PLA.

15. a) Design a 4 bit ring counter.

Differentiate between Synchronous and Asynchronous counter.

b) Design a 4 bit up ripple counter and explain its timing diagram.

## Bloom's Cognitive Levels of Learning (BCLL)

	Max.Ma	arks:20				
Understand	L2	Analyze	L4	Create	L6	
Remember	L1	Apply	L3	Evaluate	L5	

	ANSWER ALL QUESTIONS			
1	Convert the following to the decimal form.	всll L3	CO(s) CO1	Marks [2M]
	i) (01101001.101)2 ii) (A23B)16			
2	Obtain dual of the expression AB+A'C+AC+BC.	L2	CO2	[2M]
3	Draw a full subtractor logic diagram with truth table.	L4	CO3	[2M]
4	Write the properties of Bistable latch.	L2	CO4	[2M]
5	Write the applications of flip flops.	L2	CO5	[2M]
6	Differentiate between ROM, PROM.	L4	CO6	[2M]
7	Explain the Properties of XOR Gate.	L2	CO1	[2M]

## Part – B Max.Marks:50 ANSWER ANY FIVE QUESTIONS. EACH QUESTION CARRIES 10 MARKS.

		ANOTHER ANTITIVE QUEDITORO. LACIT QUEDITOR CARRIED TO MAI	<b></b>		
11.	a)	Convert (A1F9) <sub>16</sub> to decimal, binary, octal.	BCLL L3	CO(s) CO1	Marks [5M]
	b)	Realize AND,OR gates from universal gates.	L4	CO1	[5M]
12.	a)	•	L4	CO2	[5M]
	b)	$f(w, x, y, z) = \Sigma m(4, 5, 7, 12, 14, 15) + \emptyset(3, 8, 10).$ Simplify the following Boolean function $f(W,X,Y,Z) = \Sigma m(2,6,8,9,10,11,14,15)$ using Quine-McClukey method.	L4	CO2	[5M]
13.	a)	Explain the differences between a MUX and a DEMUX.	L4	CO3	[5M]
	b)	Realize a full adder using half adders and explain the truth table.	L4	CO3	[5M]
14.	a)	Explain the operation of positive triggered D-flip flop with the help of a circuit diagram.	L4	CO4	[5M]
	b)	Design a 4-bit parallel in parallel out register.	L2	CO4	[5M]

CO<sub>5</sub>

CO<sub>5</sub>

[5M]

[5M]

L4

L4

16.	a)	What is a programmable device? How it differs from ROM?	L4	CO6	[5M]		
	b)	Explain in detail sequential programmable devices.	L4	CO6	[5M]		
17.	a)	Given two binary numbers X=1010100 and Y=1000011.  Perform i)X-Y ii)Y-X using 2's complement method.	L3	CO1	[4M]		
	b)	Obtain dual of the following Boolean expressions i) AB+A(B+C) +B'(B+D) ii) A+B+A'B'C.	L3	CO2	[3M]		
	c)	Realize3-bit digital comparator and explain the truth table.	L4	CO3	[3M]		
18.	a)	Implement a JK flip flop using SR flip flop.	L4	CO4	[4M]		
	b)	Classify types of registers and define them.	L1	CO5	[3M]		
	c)	Discuss about SRAM and its usage.	L4	CO6	[3M]		
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